

Reactions of Tin(IV) Chloride with Organosilyl Compounds

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The reaction between SnCl_4 and $\text{R}_{3-n}\text{SiH}_{n+1}$ ($n = 0-2$) have been investigated [$\text{R} = \text{CH}_3, \text{CH}=\text{CH}_2, \text{CH}_2-\text{CH}=\text{CH}_2, \text{C}\equiv\text{CH}, \text{C}\equiv\text{CCF}_3, \text{C}_5\text{H}_5, \text{C}_6\text{H}_5, \text{or Si}(\text{CH}_3)_3$]; the reaction with silacyclopent-3-ene was also investigated. All the reactions led to monochlorination at silicon without breaking the Si–C and/or Si–Si bonds except in some allylsilanes, and spectroscopic parameters for the new compounds $\text{CH}_2-\text{CH}=\text{CH}-\text{CH}_2\text{SiHCl}$, $\text{CH}=\text{CSiH}_2\text{Cl}$, $\text{CF}_3\text{C}=\text{CSiH}_2\text{Cl}$, $(\text{CH}_3)_3\text{SiSiH}_2\text{Cl}$, and $(\text{CH}_3)_3\text{SiSiHCl}_2$, all prepared by this route, are reported. For the disilanes, ^{29}Si and ^{13}C chemical shifts were measured by heteronuclear double resonance.

Introduction

We have already described [1] a study of the influences of tin(IV) chloride as a chlorinating agent for inorganic compounds containing the SiH_3 group. In this paper we describe the reaction between the same reagent and a variety of organosilanes containing SiH– and Si–Si bonds with a view to establishing the range of organosilanes that can be chlorinated by tin(IV) chloride without breaking Si–Si and Si–C bonds.

Experimental

Compounds were handled in standard vacuum-systems fitted with greased taps or teflon valves; all the reactions were carried out in pyrex-glass ampoules of 30 ml capacity fitted with teflon valves, involatile substances were manipulated in evacuable glovebags or boxes under an atmosphere of dry N_2 .

Spectra were obtained by means of the following instruments: infrared, Perkin-Elmer 225 ($500-200 \text{ cm}^{-1}$) or 457; Raman, Cary 83 (Ar^+ ion laser source, 488 nm); Mass, AEI MS 902; NMR HA 100 (100 MHz for ^1H) whose probe has been double-tuned to accept a second radio-frequency [2]. Elemental analyses were obtained from Galbraith Laboratories, Knoxville, TN. All the known compounds among the products were identified by comparing their infrared and ^1H NMR spectra with those of the authentic samples.

Reaction of the Tin(IV) Chloride

With Methylsilane

Methylsilane (1.02 mmol) was allowed to warm to room temperature with SnCl_4 (1.43 mmol). A thin white film began to form almost immediately; the reaction appeared complete after 4 hr. The volatile products consisted of HCl (1.03 mmol), $\text{CH}_3\text{SiH}_2\text{Cl}$ (0.87 mmol) and $\text{CH}_3\text{SiHCl}_2$ (0.15 mmol); a white involatile residue of SnCl_2 (1.05 mmol) remained.

With Dimethylsilane

Dimethylsilane (1.00 mmol) was allowed to warm to room temperature with SnCl_4 (1.16 mmol). A white solid began to form almost at once and the reaction appeared complete after 20 minutes. The volatile products consisted of HCl (1.00 mmol) and $(\text{CH}_3)_2\text{SiHCl}$ (1.00 mmol); a white involatile residue of SnCl_2 (1.00 mmol) remained.

With Trimethylsilane

Trimethylsilane (1.00 mmol) was allowed to warm to room temperature with SnCl_4 (1.40 mmol). A thin white film of solid began to form almost at once; the reaction appeared complete after 3 hr. The volatile products consisted of HCl (1.00 mmol) and Me_3SiCl (1.00 mmol); SnCl_4 (0.31 mmol) was

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TABLE I. Raman and Infrared Spectra of $\text{ClSiH}_2\text{C}\equiv\text{CH}$.

Liquid ^a		Vapor ^a	
Raman frequency (cm^{-1})	Raman polarization ratio	Infrared frequency (cm^{-1})	Possible assignments
3310 vvw	p?	3313.8 s	νCH
		2247.3 w	?
2220 vvs	p	2219.1 vs	νSiH (asym)
		2215 s	νSiH (sym)
		2204.4 s	?
2060 vs	p	2061.8 s	$\nu\text{C}\equiv\text{C}$
		1362 m	2×692 (overtone)
950 \pm 1 s, broad	dp?	955 s	δSiH_2
		934 \pm 1 m	?
870 w, broad	dp?	874.6 vs	δSiH_2
		815 vw	δSiH_2
810 vvw, broad	dp?		
735 m, broad	dp?	729.8 vw	C_2H_2 impurity
710 w, broad	dp?	692 s	ρSiH_2
670 \pm 2 w	p?	663 w	νSiC
620 \pm 5 vw, broad	dp?	628? m	δCCH (asym)
		615 m	δCCH (sym)
535 vvs	p	548 m	νSiCl
325 w, broad	p?	322 w	SiCC bend (asym)
222 s	dp?		SiCC bend (sym)
132 vs	dp?		ClSiC bend

^aWhere s = strong, m = medium, w = weak, v = very, p = polarised and dp = depolarised.

recovered, and a residue of SnCl_2 (1.00 mmol) remained.

With Methylchlorosilane

Methylchlorosilane (0.37 mmol) was allowed to warm to room temperature with SnCl_4 (0.39 mmol). A white solid began to form slowly. After 3 days, the products were found to consist of HCl (0.21 mmol) and $\text{CH}_3\text{SiHCl}_2$ (0.23 mmol); $\text{CH}_3\text{SiH}_2\text{Cl}$ (0.13 mmol) and SnCl_4 (0.15 mmol) were recovered, and a residue of SnCl_2 remained. In a separate experiment, $\text{CH}_3\text{SiH}_2\text{Cl}$ (0.80 mmol) was allowed to stand over SnCl_2 (2.0 mmol); all the $\text{CH}_3\text{SiH}_2\text{Cl}$ (0.80 mmol) was recovered unchanged.

With Vinylsilane

Vinylsilane (1.00 mmol) and SnCl_4 (1.50 mmol) were allowed to warm to room temperature; white solid began to form at once and the reaction appeared complete after 18 hours. The volatile products consisted of HCl (1.11 mmol), SiH_3Cl (0.11 mmol), vinylchlorosilane (0.67 mmol), and vinylchlorosilane (0.21 mmol); unreacted SnCl_4 (0.25 mmol) was recovered. In a second experiment, vinylsilane

(2.00 mmol) and SnCl_4 (1.50 mmol) gave HCl (1.50 mmol), $\text{ClSiH}_2\text{CHCH}_2$ (1.50 mmol) and vinylsilane (0.50 mmol).

With Allylsilane

Allylsilane (1.00 mmol) and SnCl_4 (1.2 mmol) were allowed to warm together to room temperature. A white solid began to form at once; the reaction appeared complete after 2 hours. The volatile products consisted of HCl (0.12 mmol), SiH_3Cl (0.60 mmol), SiH_2Cl_2 (0.40 mmol) and $\text{ClCH}_2\text{-CHCH}_2$ (0.80 mmol); a white involatile residue of SnCl_2 remained.

With Phenylsilane

Phenylsilane (1.00 mmol) and SnCl_4 (1.50 mmol) were allowed to warm together to room temperature. A thin white film began to form almost at once; the reaction appeared complete after 15 minutes. The volatile products were found to consist of HCl (0.92 mmol), SiH_3Cl (0.04 mmol), SiH_2Cl_2 (0.02 mmol) and PhSiH_2Cl (0.91 mmol); SnCl_4 contaminated with a little benzene (0.5 mmol in all) was also recovered, and a residue of involatile SnCl_2 remained.

TABLE II. Raman and Infrared Spectra of ClSiH₂CCCF₃.

Liquid ^a		Vapor ^a	
Raman frequency (cm ⁻¹)	Raman polarization ratio	Infrared frequency (cm ⁻¹)	Possible assignments
2238 vs	p	2226 s	ν SiH (asym)
		2221.5 s	ν SiH (sym) + ν C \equiv C
1265 vvw, br	dp	1252.6 vs	
1225 vvw	dp	1223 s	ν C-F
1172 vw, br	dp	1180 vvs	
948 s	dp	947 s	δ SiH ₂
880 s	p	—	?
865 m	dp	868 vs	δ SiH ₂
742 m	p	760 vvw	δ SiH ₂
731 m	dp	726 vvw	ρ SiH ₂
702 w	p	698 vvw	ν SiC
620 m	dp	610 m	δ CF ₃
558 vs	p	564 s	ν SiCl
462 m	dp	467 vvw	δ CF ₃
378 m	dp?	372 m	δ CF ₃
305 vs	p	302 vvw	CCC bend?
243 \pm 1 vvs	dp	—	SiCC bend?
151 vvs	dp?	—	ClSiC bend?

^aWhere s = strong, m = medium, w = weak, br = broad, v = very, p = polarised, and dp = depolarised.

With Cyclopentadienylsilane

Cyclopentadienylsilane (0.50 mmol) was allowed to warm with SnCl₄ (0.70 mmol) to room temperature. A grey-white solid formed immediately, and this reaction was complete in 3 minutes. The volatile products were found to consist of HCl (0.07 mmol), SiH₃Cl (0.43 mmol) and SiH₂Cl₂ (0.07 mmol). Attempts to record the infrared spectrum of the solid residue were unsuccessful.

With Silacyclopent-3-ene

Silacyclopent-3-ene (1.00 mmol) and SnCl₄ (1.03 mmol) were allowed to warm together to room temperature. A white solid began to form at once and reaction appeared complete after 30 minutes. The volatile products were found to consist of HCl (volatile at -78 °C) and 1-chlorosilacyclopent-3-ene [collected in a trap at -78 °C, 1.00 mmol. Exact mass M.W. for ³⁵Cl²⁸SiC₄H₇, ³⁷Cl²⁸SiC₄H₇, Calc. 118.000555, 119.997605; Found: 118.000813, 119.997921. ¹H NMR spectrum, SiH triplet (J = 2.8 Hz) at δ 4.67 ppm, multiplets δ 1.9 and δ 4.8–6 ppm. Raman peaks at 3054m, 2918sp, 2195vs, 1612m, 1405m, 1285sh, 1211mp, 918s, 763m, 718vs, 640s, 530wsp, 235m, 197s. IR peaks at 2960sh, 2850sh, 2175s, 1108m, 857s, 755m, 643m, 528m. Anal. Calcd. for C₄H₇ClSi: C, 40.51; H, 5.91;

Cl, 29.95; Si, 23.63. Found: C, 40.54; H, 5.82; Cl, 29.89; Si, 23.66].

With Silylacetylene

Silylacetylene (1.00 mmol) was allowed to warm to room temperature with SnCl₄ (1.50 mmol). White solid began to form at once; the reaction appeared complete after 18 hours. The volatile products consisted of HCl (volatile at -130 °C, 0.50 mmol), SiH₃Cl (volatile at -120 °C, 0.07 mmol), unreacted silylacetylene (volatile at -120 °C, 0.43 mmol), and chlorosilylacetylene [volatile at -78 °C but involatile at -120 °C, 0.50 mmol. M(Dumas), found 91.3; calc. 90.5. M(exact mass), ³⁵Cl²⁸SiC₂H₃, ³⁷Cl²⁸SiC₂H₃, found, 89.968993, 91.966740; calc. 89.969256, 91.966306. v.p. at 0 °C, 16.2 cm Hg; b.p. (extrap.) = 321 K. δ (SiH) = 4.79, δ (CH) = 2.48 ppm. (Me₄Si solvent and internal standard); ⁴J(HH) = 1.0 Hz. Vibrational spectra and assignments are summarized in Table I. Anal. calcd for C₂H₃ClSi: C, 26.52; H, 3.31; Cl, 39.23; Si, 30.94. Found: C, 26.43; H, 3.42; Cl, 39.19; Si, 31.02].

With 1-Silyl-3,3,3-trifluoropropyne

1-silyl-3,3,3-trifluoropropyne (1.0 mmol) was allowed to warm to room temperature with SnCl₄ (0.95 mmol); white solid began to form at once and

TABLE III. Raman and Infrared Spectra of Me₃SiSiH₂Cl.

Liquid ^a		Vapor ^a	
Raman frequency (cm ⁻¹)	Raman polarization ratio	Infrared frequency (cm ⁻¹)	Possible assignments
2970 s	dp	2958 ± 1 m	νCH
2910 s	p	2900 w	
		2869 vvw	
2140 ± 2 vs	p	2138 ± 1 s	νSiH
1410 w,br	dp	1410 w,br	δCH ₃ (asym)
		1325 ± 1 vvw	
1265 w	p?	1262 m	δCH ₃ (sym)
1252 w	dp		
940 m,br	dp	945 ± 2 w,br	δSiH ₂
870sh			
845 vw,br	dp	845 s,br	ρCH ₃
805 ± 2 vw	p?	802 ± 2 vs	δSiH ₂
755 vw	dp	743 w	ρ SiH ₂ ?
702 s	dp	698 w	νSiC
630 vs	p	620 w	νSiC
525 ± 2 m,br	dp?	530 ± 1 m	νSiCl
478 m	p	490 vvw	?
418 vvs	p	405 vvw	νSi-Si
223 vs	dp		
180 s	p?		δC ₃ Si
150s	dp?		ClSiSi bend?

^aWhere s = strong, m = medium, w = weak, sh = shoulder, br = broad, p = polarised and dp = depolarised.

the reaction appeared complete after 18 hours. The volatile products consisted of HCl (collected in a -196 °C trap, 0.95 mmol), unreacted SiH₃CCCF₃ (collected in a -120 °C trap, 0.05 mmol), and 1-chlorosilyl-3,3,3-trifluoropropyne [volatile at -78 °C but involatile at -96 °C, 0.95 mmol. M(Dumas), found, 158; required 158.5. M(exact mass mass spectrum), 157.956151, 159.953273. C₃H₂ClF₃Si requires 157.956638 (³⁵Cl), 159.953688 (³⁷Cl). ^δ(Me₄Si solvent and standard), 4.88; ^δF, -53.42 (low frequency of CCl₃F solvent and standard) ¹J(²⁹SiH) = 265, ⁵J(HF) = 1.3 Hz. Vibrational frequencies and assignments are summarised in Table II. Anal. Calcd for C₃H₂ClF₃Si: C, 22.71; H, 1.26; Cl, 22.40; F, 35.96; Si, 17.67. Found: C, 22.80; H, 1.30; Cl, 22.38; F, 35.89; Si, 17.70].

With 1,1,1-Trimethyldisilane

1,1,1-trimethyldisilane (1.0 mmol) and SnCl₄ (0.96 mmol, 0.258 g) were condensed in a 20-ml reaction ampoule and allowed to warm to room

temperature. A thin white film on the inner walls of the reaction ampoule began to form almost immediately, and the reaction was complete in 5 minutes. Trap-to-trap distillation of the volatile products gave HCl (0.96 mmol) volatile at -120 °C, unreacted Me₃SiSiH₃ (0.04 mmol) volatile at -78 °C, and Me₃SiSiH₂Cl [0.96 mmol, collected in a -78 °C trap. M(Dumas), found 139; required 138.5. M (exact mass), 138.008335, 140.006094. C₃H₁₁ClSi₂ requires 138.008782 (³⁵Cl), 140.005832 (³⁷Cl). ¹H NMR spectrum (C₆H₆ solvent and standard, SiH [¹J(H²⁹Si) = 204 Hz; ²J(HSi²⁹Si) = 11 Hz] singlet at δ 4.66 ppm, HCSi singlet at δ 0.02 ppm; ¹J(H¹³C) = 120 Hz, ²J(HC²⁹Si) = 6.6 Hz, ³J(HCSi²⁹Si) = 3.8 Hz. ^δ²⁹Si (relative to Me₄Si; negative to low frequency Me₃²⁹Si²⁹SiH₂Cl = -30.75 ppm, Me₃²⁹-Si²⁸SiH₂Cl = -15.7 ppm. ^δ¹³C = -5.52 ppm. Vibrational frequencies and assignments are summarized in Table III. Anal. calcd. for C₃H₁₁ClSi₂: C, 26.0; H, 7.9; Cl, 25.6; Si, 40.4. Found: C, 26.1; H, 7.8; Cl, 25.5; Si, 40.5.]

TABLE IV. Raman and Infrared Spectra of Me₃SiSiHCl₂.

Liquid ^a		Vapour ^a	
Raman frequency (cm ⁻¹)	Raman polarization ratio	Infrared frequency (cm ⁻¹)	Possible assignments
2965 m	dp	2968 ± 2 w	νCH
2902 s	p	2910 ± 2 vw	
		2850 vvw	
2170 vs	p	2171 ± 2 m	νSiH
1415 ± 5 vw,br	dp	1405 vvw	δCH ₃ (asym)
1250 ± 5 vw,br	dp	1258 m	δCH ₃ (sym)
1055 vvw	dp?		?
915 vvw,br	dp?		
850 ± 5 vw,br	dp?	865 sh	δSiH
		845 m	
775 w	dp	778 s	ρCH ₃
738 m	dp	734 m	ρSiH
702 w	dp	704 sh	νSiC
625 vs	p	622 vw	νSiC
542 sh	dp?	558 s	νSiCl (asym)
525 m	p?	532 m	νSiCl (sym)
392 vvs	p	395 vvw	νSi-Si
258 m	dp?	-	?
215 s	dp?	-	δC ₃ Si
178 m	dp?	-	
152 s	dp?	-	
095? vw	p?	-	ClSiSi bend
			ClSiCl bend?

^aWhere s = strong, m = medium, w = weak, sh = shoulder, br = broad, v = very, p = polarised and dp = depolarised.

With 1,1,1-Trimethyl-2-chlorodisilane

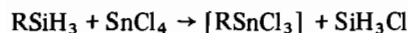
Me₃SiSiH₂Cl (1.0 mmol) was allowed to warm to room temperature with SnCl₄ (1.03 mmol, 0.27 g); white solid began to form slowly and the reaction appeared complete after 24 hours. The volatile products consisted of HCl (collected in a trap at -196 °C, 1.0 mmol), and Me₃SiSiHCl₂ [volatile at -45 °C but involatile at -78 °C, 1.0 mmol. M(Dumas), found, 173; required 173. M(exact mass), 171.969783, 173.966723, 175.964341. C₃H₁₀Cl₂Si₂ requires 171.969810 (³⁵Cl, ³⁵Cl), 173.966854 (³⁵Cl, ³⁷Cl), 175.963910 (³⁷Cl, ³⁷Cl). ¹H NMR spectrum (C₆H₆ solvent and standard), SiH [¹J(H²⁹Si) = 235 Hz; ²J(HSi²⁹Si) = 18.8 Hz] singlet at δ 5.58 ppm, HCSi [²J(HC²⁹Si) = 7.0 Hz; ²J(HCSi²⁹Si) = 5.0 Hz; ¹J(H¹³C) = 121 Hz] singlet at δ -0.01 ppm. ²⁹Si (relative to Me₄Si; negative to low frequency) Me₃²⁸Si²⁹SiHCl₂ = +12.08 ppm, Me₃²⁹Si²⁸SiHCl₂ = -6.54. ¹³C = -3.78 ppm. Vibrational frequencies and assignments are summarized in Table IV. *Anal.* calcd for C₃H₁₀Cl₂Si₂: C, 20.8; H, 5.78; Cl, 41.0; Si, 32.4. Found: C, 20.8; H, 5.75; Cl, 40.9; Si, 32.5].

Discussion

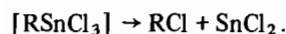
Our results suggest that tin(IV) chloride is a convenient reagent for chlorinating SiH-groups in organosilanes other than some allylsilanes; cyclopentadienylsilane can be regarded as an allylsilane. As with inorganic molecules containing SiH₃-groups, reaction to introduce a single chlorosubstituent at a silicon atom is much faster than to introduce a second. We made no quantitative studies of rates of reaction; however, it is clear that reaction between SnCl₄ and Me_{3-n}SiH_{n+1} (n = 0-2) is fastest when n = 1. It seems likely that the rate of reaction depends on a combination of steric and electronic factors. This would explain why the rate increases with increasing methyl substitution at silicon until steric factors become important. This is consistent with a mechanism involving electrophilic attack at silicon. The observation that the Sn(II) chloride produced forms an adherent film on the ampoule wall suggests that reaction occurs predominantly in a liquid film of Sn(IV) chloride. The product SnCl₂ + HCl might be formed by decomposition of an initial product

HSnCl_3 , but we have obtained no evidence for the formation of this species.

The cleavage of the Si—C bonds in allylsilane and cyclopentadienylsilane may involve initial formation of organotin(IV) derivatives:



We were unable to identify such a derivative in either case. The isolation of allyl chloride in 80% yield from reaction of allylsilane and tin(IV) chloride would then imply the ready decomposition.



The reaction with silylcyclopentadiene yielded no chlorocyclopentadiene; the possibility of polymerization complicates the problem in this case.

It is interesting that significant quantities of SiH_2Cl_2 were found in the reactions of allylsilane and cyclopentadienylsilane. These could not have been formed indirectly by reaction of initially-formed SiH_3Cl with unreacted SnCl_4 , as this reaction is very slow. It may be that the postulated intermediate $[\text{RSnCl}_3]$ is a better chlorinating agent than SnCl_4 . We intend to investigate this point using alkyl substituted tin(IV) chloride.

References

- 1 S. Cradock, E. A. V. Ebsworth and N. S. Hosmane, *J. Chem. Soc. Dalton Trans.*, 16/17, 1624 (1975).
- 2 D. E. J. Arnold, J. S. Dryburgh, E. A. V. Ebsworth and D. W. H. Rankin, *J. Chem. Soc., Dalton Trans.*, 2518 (1972).